

2SK2195
(FP15W50VX2)

500V 15A

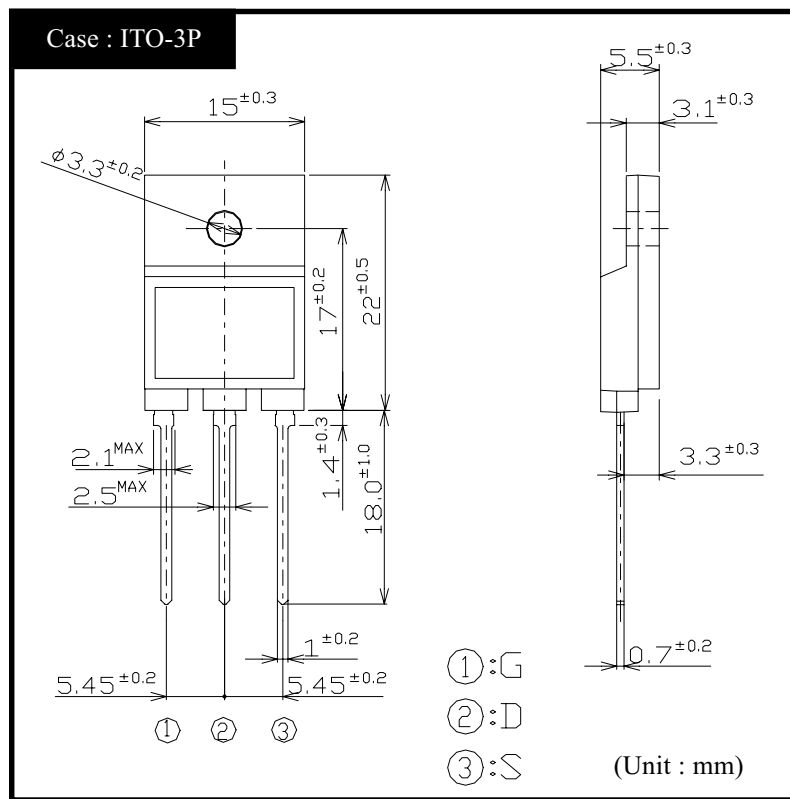
FEATURES

- Input capacitance (Ciss) is small.
Especially, input capacitance at 0 bias is small.
- The static Rds(on) is small.
- The switching time is fast.

APPLICATION

- Switching power supply of AC 100V input
- High voltage power supply
- Inverter

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings (Tc = 25°C)

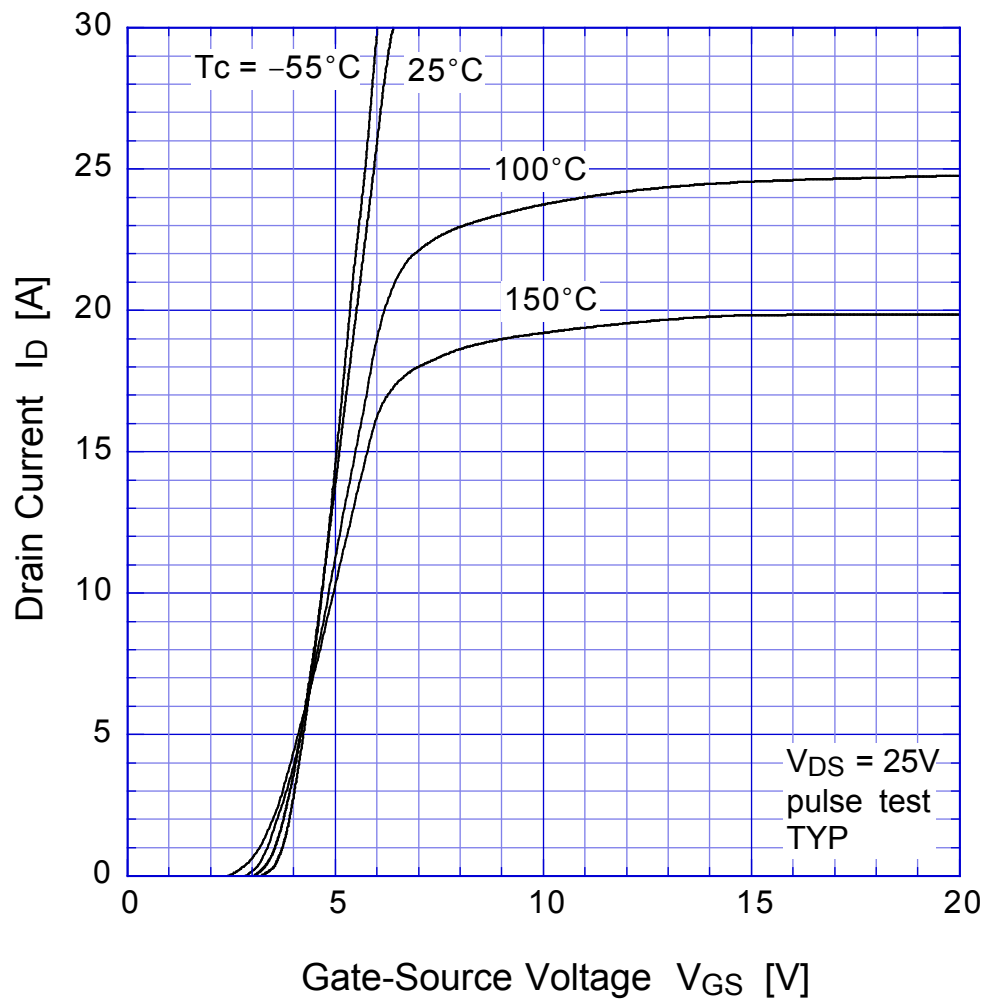
| Item | Symbol | Conditions | Ratings | Unit |
|---------------------------------|------------------|---------------------------------|---------|------|
| Storage Temperature | T _{stg} | | -55~150 | °C |
| Channel Temperature | T _{ch} | | 150 | |
| Drain-Source Voltage | V _{DSS} | | 500 | V |
| Gate-Source Voltage | V _{GSS} | | ±30 | |
| Continuous Drain Current (DC) | I _D | | 15 | A |
| Continuous Drain Current (Peak) | I _{DP} | | 45 | |
| Continuous Source Current (DC) | I _S | | 15 | |
| Total Power Dissipation | P _T | | 60 | W |
| Single Pulse Avalanche Current | I _{AS} | T _{ch} = 25°C | 15 | A |
| Dielectric Strength | V _{dis} | Terminals to case, AC 1 minute | 2 | kV |
| Mounting Torque | TOR | (Recommended torque : 0.5N·m) | 0.8 | N·m |

●Electrical Characteristics $T_c = 25^{\circ}\text{C}$

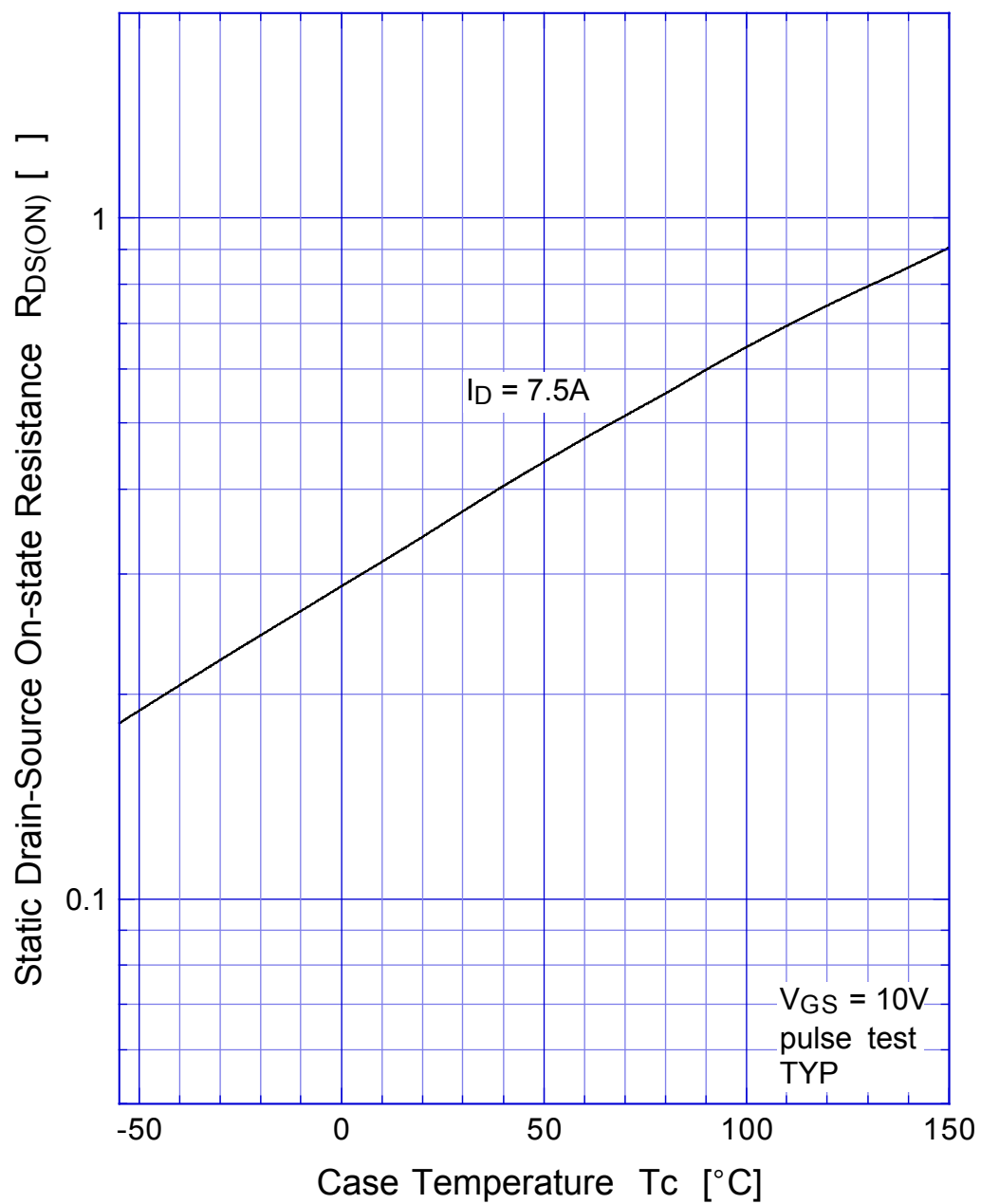
| Item | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|---|---------------|---|------|------|-----------|-----------------------------|
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$ | 500 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 500\text{V}$, $V_{GS} = 0\text{V}$ | | | 250 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$ | | | ± 0.1 | |
| Forward Transconductance | g_{fs} | $I_D = 7.5\text{A}$, $V_{DS} = 10\text{V}$ | 4.5 | 10 | | S |
| Static Drain-Source On-state Resistance | $R_{DS(ON)}$ | $I_D = 7.5\text{A}$, $V_{GS} = 10\text{V}$ | | 0.35 | 0.45 | Ω |
| Gate Threshold Voltage | V_{TH} | $I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$ | 2.5 | 3.0 | 3.5 | V |
| Source-Drain Diode Forwade Voltage | V_{SD} | $I_S = 7.5\text{A}$, $V_{GS} = 0\text{V}$ | | | 1.5 | |
| Thermal Resistance | θ_{jc} | junction to case | | | 2.08 | $^{\circ}\text{C}/\text{W}$ |
| Total Gate Charge | Q_g | $V_{DD} = 400\text{V}$, $V_{GS} = 10\text{V}$, $I_D = 15\text{A}$ | | 65 | | nC |
| Input Capacitance | C_{iss} | $V_{DS} = 10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$ | | 1900 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 135 | | |
| Output Capacitance | C_{oss} | | | 400 | | |
| Turn-On Time | t_{on} | $I_D = 7.5\text{A}$, $V_{GS} = 10\text{V}$, $R_L = 20\Omega$ | | 110 | 180 | ns |
| Turn-Off Time | t_{off} | | | 270 | 440 | |

2SK2195

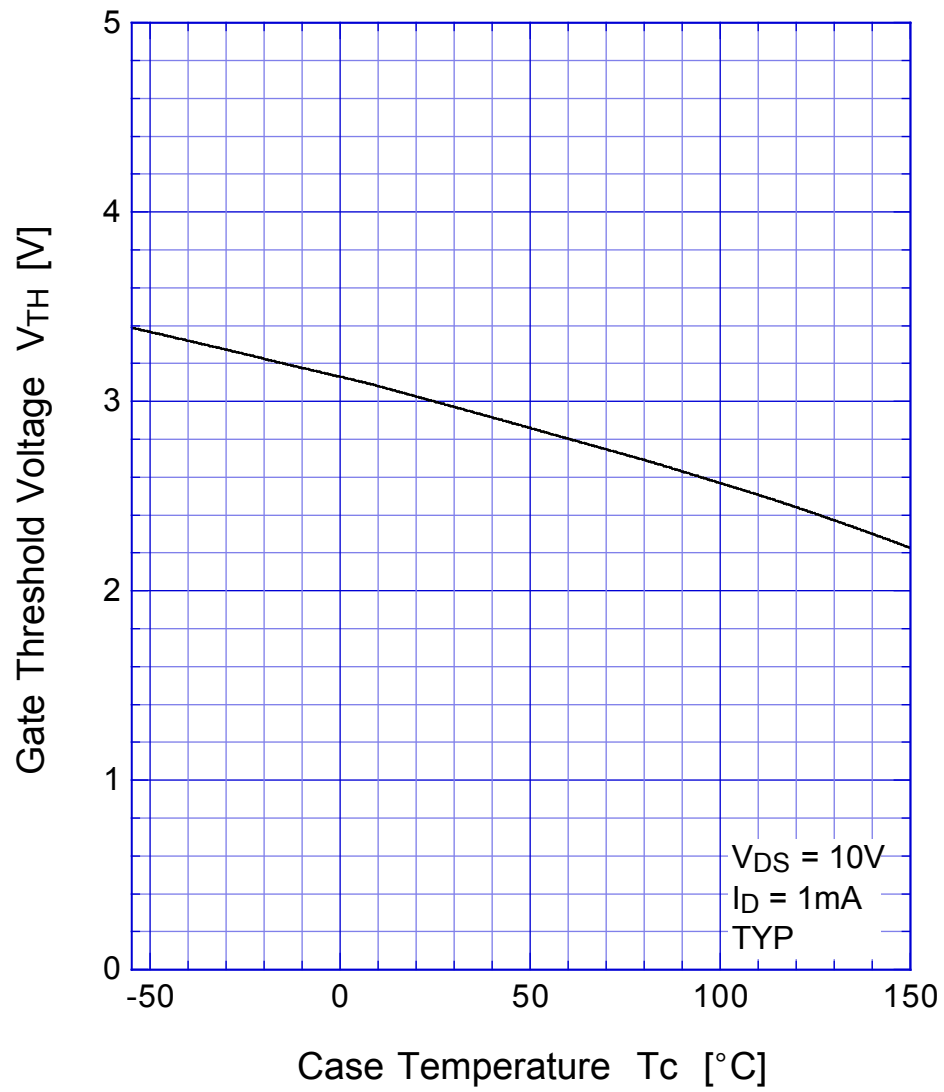
Transfer Characteristics



2SK2195 Static Drain-Source On-state Resistance

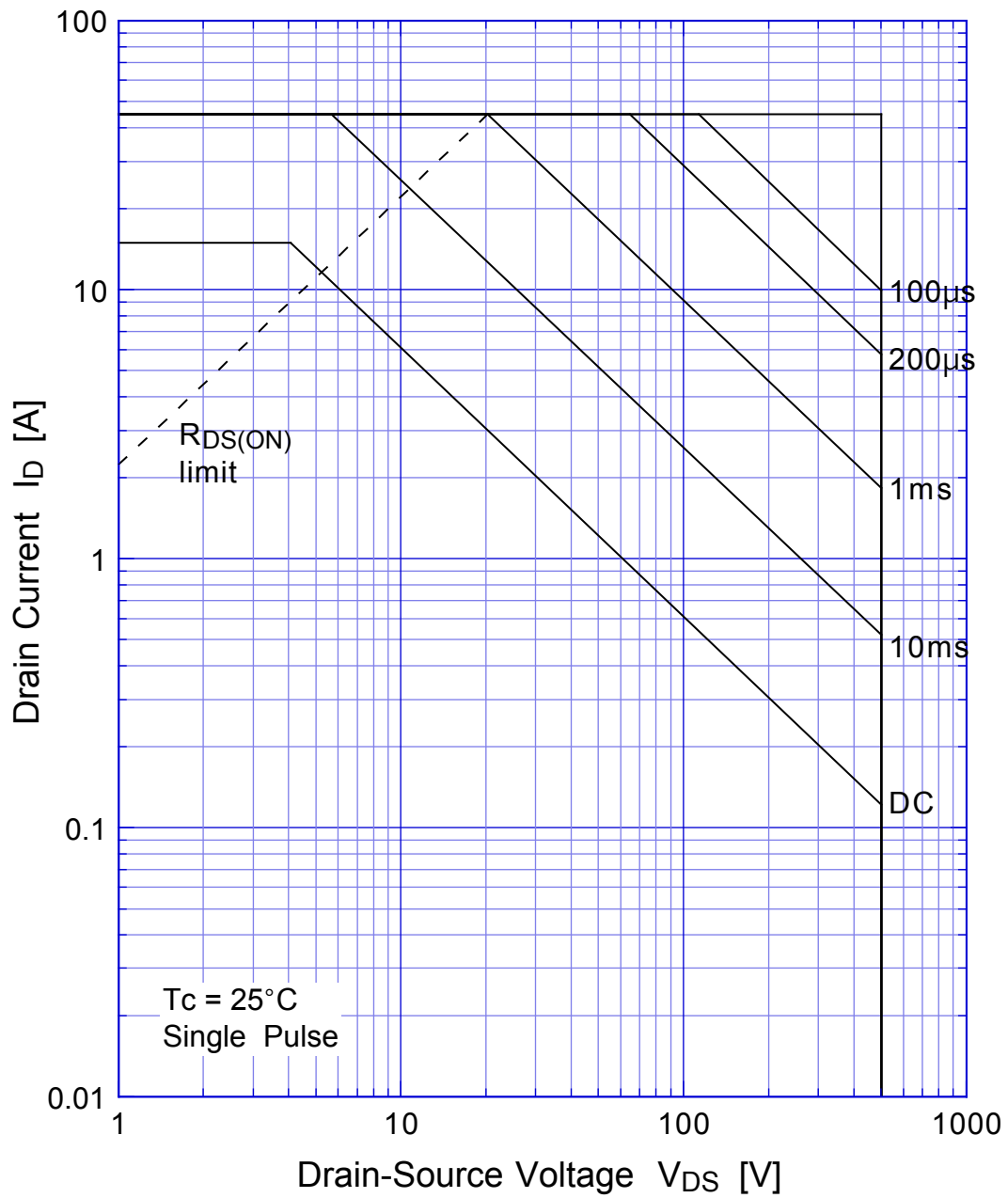


2SK2195 Gate Threshold Voltage

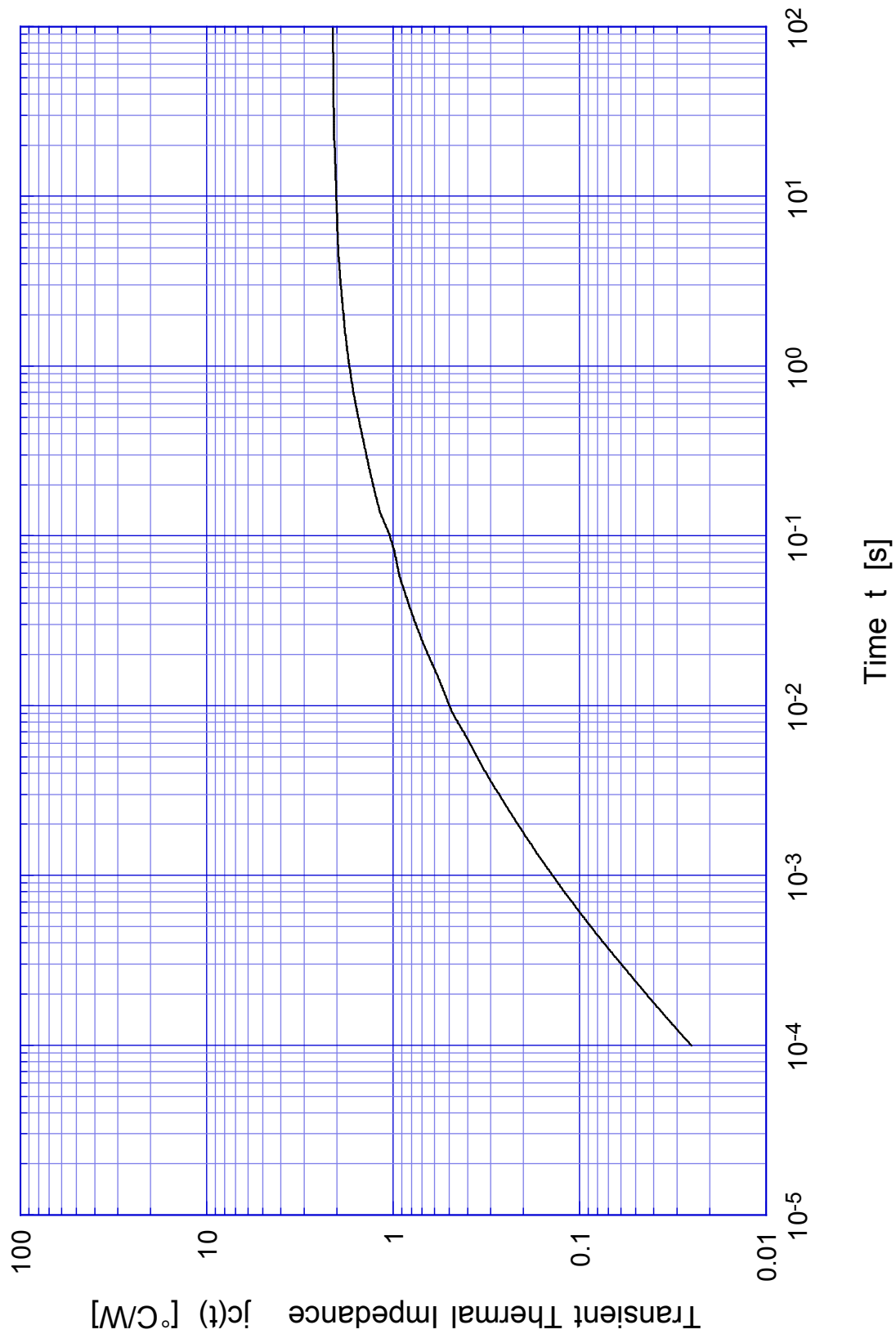


2SK2195

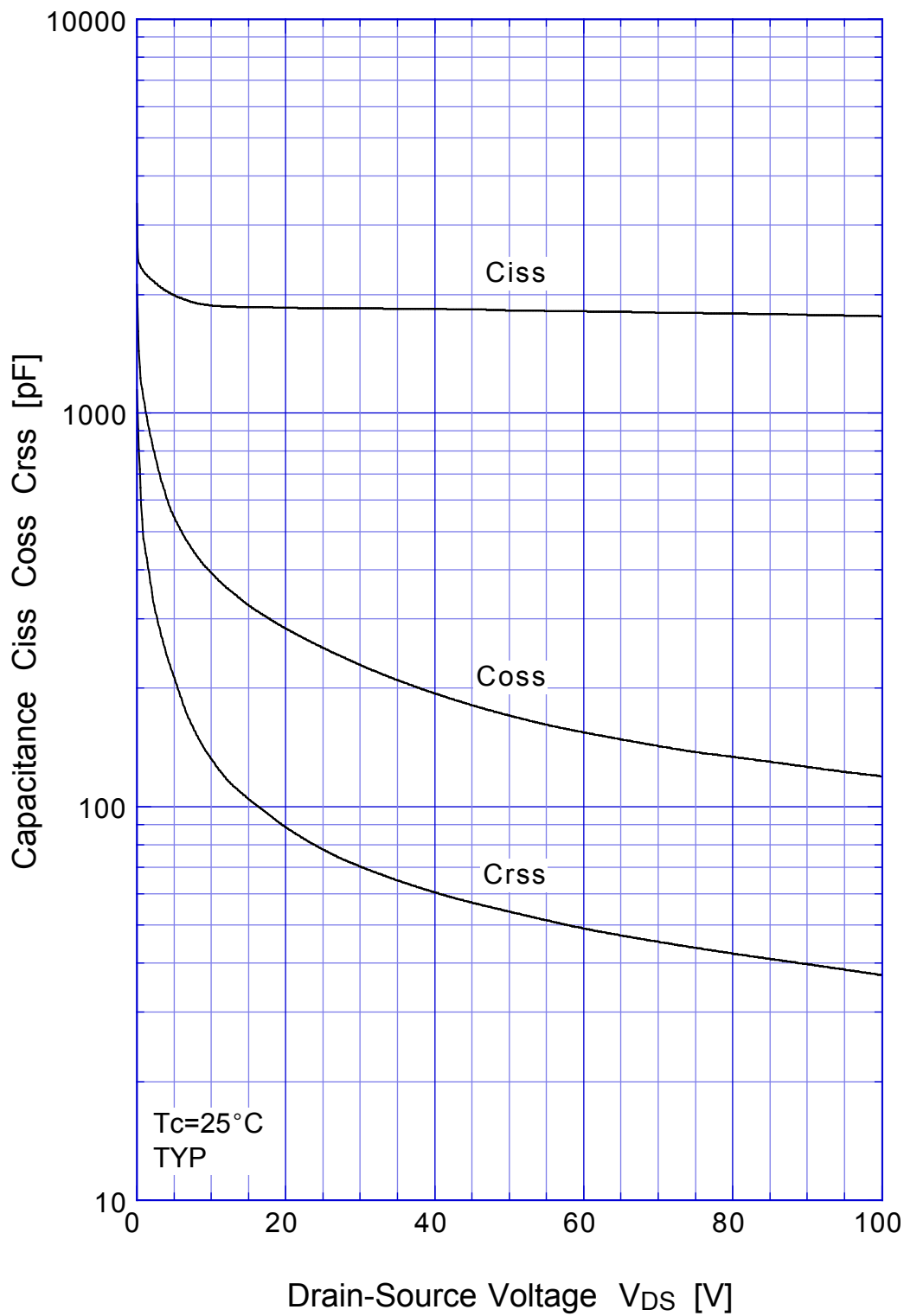
Safe Operating Area



2SK2195 Transient Thermal Impedance

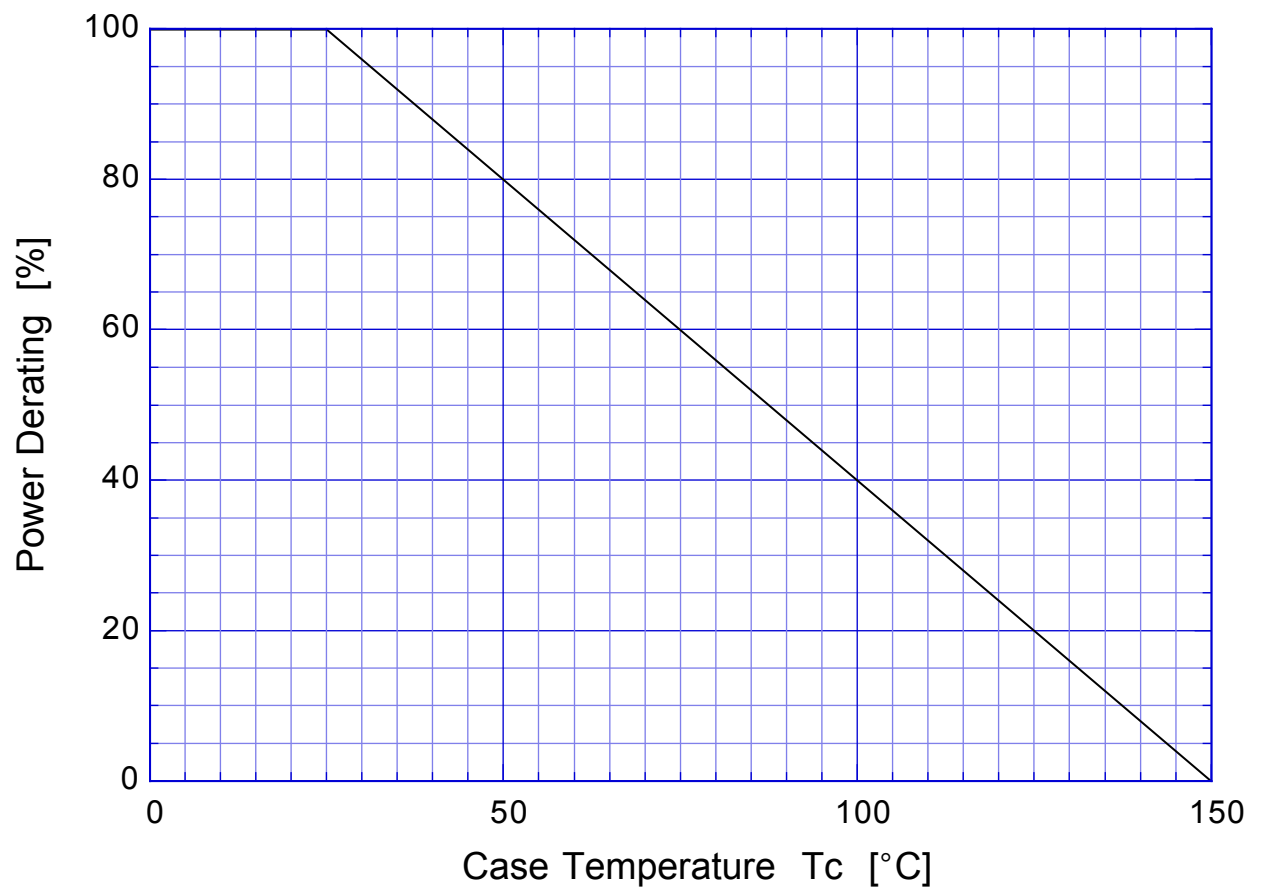


2SK2195 Capacitance



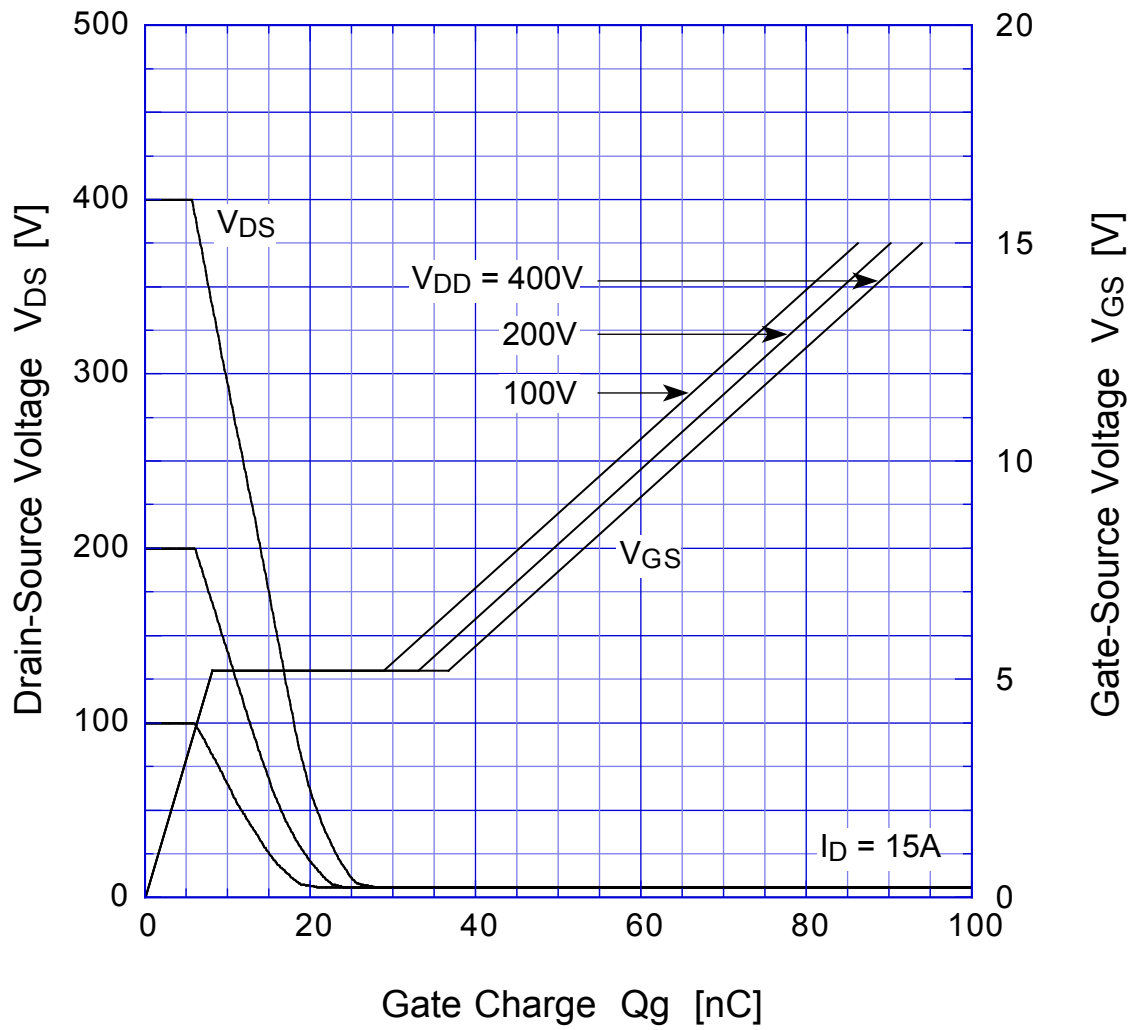
2SK2195

Power Derating



2SK2195

Gate Charge Characteristics



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.